



60V N-Channel Enhancement Mode MOSFET

Voltage

60 V

Current

40 A

Features

- $R_{DS(ON)}$, $V_{GS}@10V$, $I_D@20A<17m\Omega$
- $R_{DS(ON)}$, $V_{GS}@4.5V$, $I_D@10A<20m\Omega$
- High switching speed
- Improved dv/dt capability
- Low reverse transfer capacitance
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard



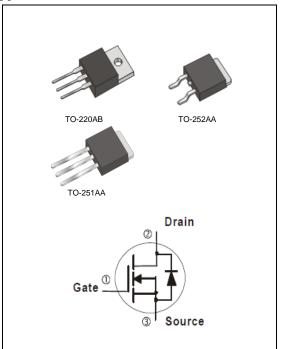
• Case: TO-251AA, TO-252AA, TO-220AB, Package

• Terminals : Solderable per MIL-STD-750, Method 2026

• TO-251AA Approx. Weight: 0.0104 ounces, 0.297grams

• TO-252AA Approx. Weight: 0.0104 ounces, 0.297grams

• TO-220AB Approx. Weight: 0.067 ounces, 2 grams



Maximum Ratings and Thermal Characteristics (T_A=25°C unless otherwise noted)

PARAMETER		SYMBOL	TO-251AA	TO-220AB	TO-252AA	UNITS
Drain-Source Voltage		V_{DS}		V		
Gate-Source Voltage		V_{GS}				
Continuous Drain Current	T _C =25°C	I _D	40	50	40	A
	T _C =100°C		25	32	25	
Pulsed Drain Current	T _C =25°C	I _{DM}	160]
Power Dissipation	T _C =25°C	PD	60	93	60	W
	T _C =100°C		24	37	24	
Single Pulse Avalanche Energy (Note 6)		E _{AS}	45			mJ
Operating Junction and Storage Temperature Range		T_{J} , T_{STG}	-55~150			°C
Typical Thermal Resistance						
- Junction to Case		$R_{ heta JC}$	2.1	1.34	2.1	°C/W
- Junction to Ambient		$R_{\theta JA}$	110	62.5	110	

• Limited only By Maximum Junction Temperature





Electrical Characteristics (T_A=25 °C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V, I _D =250uA	60	-	-	V
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$, $I_{D}=250uA$	1.0	1.7	2.5	
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =10V, I _D =20A	-	13	17	mΩ
		V _{GS} =4.5V, I _D =10A	-	16	20	
Zero Gate Voltage Drain Current	I_{DSS}	V _{DS} =60V, V _{GS} =0V	-	-	1.0	uA
Gate-Source Leakage Current	I_{GSS}	$V_{GS} = +20V, V_{DS} = 0V$	-	-	<u>+</u> 100	nA
Dynamic (Note 7)						
Total Gate Charge	Qg		-	13.5	-	nC
Gate-Source Charge	Q_{gs}	V_{DS} =30V, I_{D} =10A, V_{GS} =4.5V (Note 1,2)	-	4.8	-	
Gate-Drain Charge	$Q_{\sf gd}$	V _{GS} =4.5 V	-	4.9	-	
Input Capacitance	Ciss	\/ OF\/ \/ O\/	-	1574	-	pF
Output Capacitance	Coss	$V_{DS}=25V$, $V_{GS}=0V$,	-	118	-	
Reverse Transfer Capacitance	Crss	f=1.0MHZ	-	77	-	
Turn-On Delay Time	td _(on)	\/ 45\/ L 4A	-	11	-	
Turn-On Rise Time	$V_{DD}=15V$, $I_{D}=1A$,		-	11	-	
Turn-Off Delay Time	td _(off)	V_{GS} =10V, R_{G} =6 Ω	-	35	-	ns
Turn-Off Fall Time	t _f		-	8.1	-	
Drain-Source Diode						
Maximum Continuous Drain-Source			-	-	40	А
Diode Forward Current	I _S					
Diode Forward Voltage	V_{SD}	I _S =1A, V _{GS} =0V	-	0.68	1	V

NOTES:

- 1. Pulse width<a>300us, Duty cycle<a>2%
- 2. Essentially independent of operating temperature typical characteristics.
- 3. Repetitive rating, pulse width limited by junction temperature $T_{J(MAX)}$ =150°C. Ratings are based on low frequency and duty cycles to keep initial T_J =25°C.
- 4. The maximum current rating is package limited.
- 5. RΘ_{JA} is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch² with 2oz.square pad of copper.
- 6. The test condition is L=0.1mH, I_{AS} =30A, V_{DD} =25V, V_{GS} =10V
- 7. Guaranteed by design, not subject to production testing.





TYPICAL CHARACTERISTIC CURVES

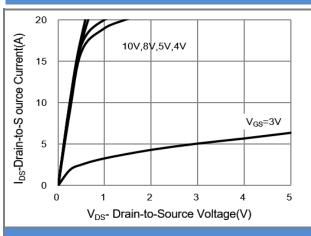


Fig.1 Output Characteristics

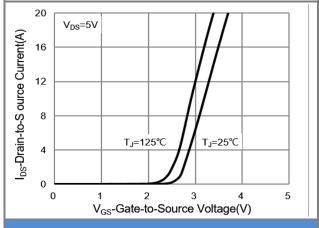


Fig.2 Transfer Characteristics

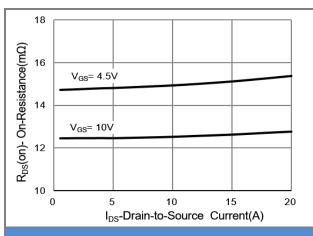


Fig.3 On-Resistance vs. Drain Current

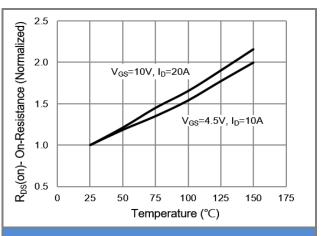
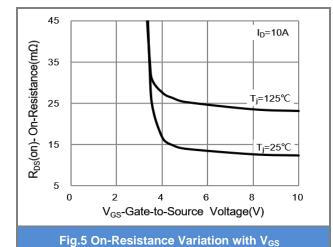


Fig.4 On-Resistance vs. Junction temperature



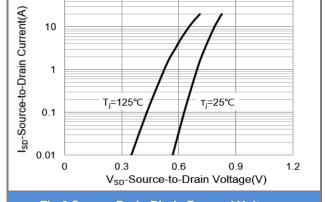


Fig.6 Source-Drain Diode Forward Voltage

100





TYPICAL CHARACTERISTIC CURVES

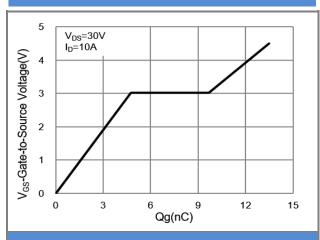


Fig.7 Gate-Charge Characteristics

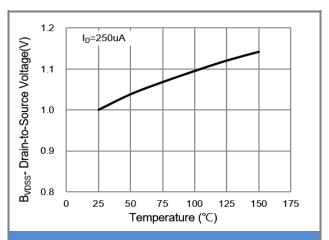


Fig.8 Breakdown Voltage Variation vs. Temperature

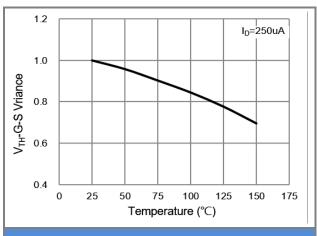


Fig.9 Threshold Voltage Variation with Temperature

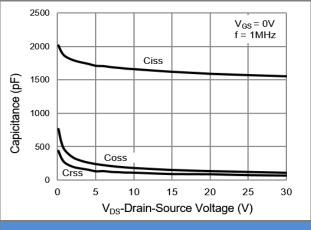


Fig.10 Capacitance vs. Drain-Source Voltage

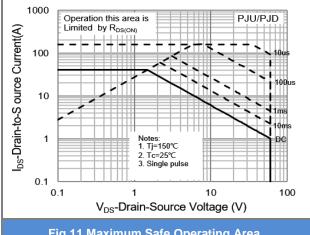


Fig.11 Maximum Safe Operating Area

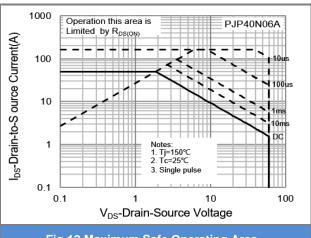


Fig.12 Maximum Safe Operating Area





TYPICAL CHARACTERISTIC CURVES

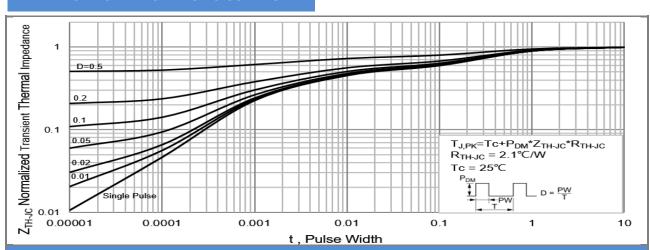


Fig.13 PJD/PJU Normalized Transient Thermal Impedance vs. Pulse Width

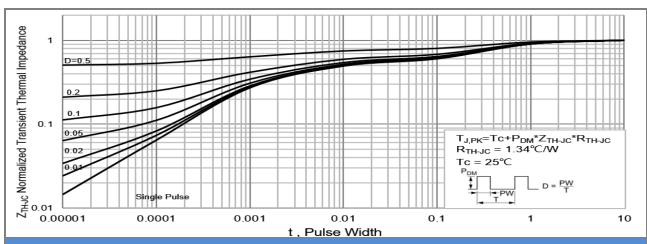


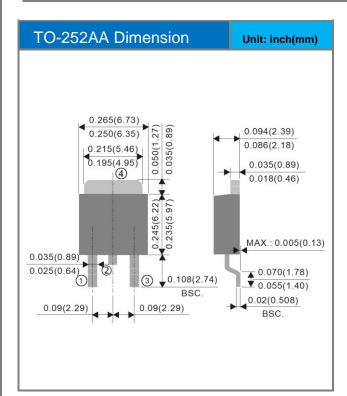
Fig.14 PJP40N06A Normalized Transient Thermal Impedance vs. Pulse Width

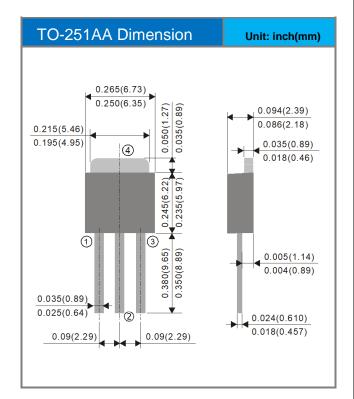
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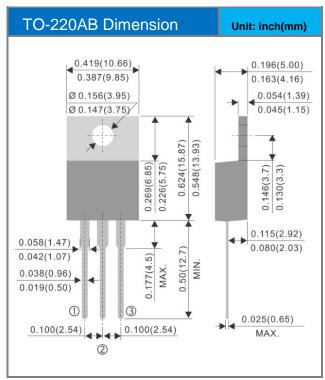




Packaging Information







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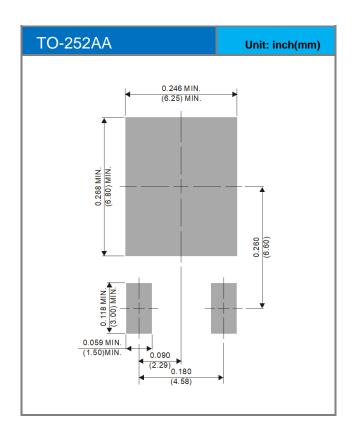




Part No Packing Code Version

Part No Packing Code	Package Type	Packing Type	Marking	Version
PJU40N06A_T0_00001	TO-251AA	80pcs / Tube	U40N06A	Halogen free
PJD40N06A_L2_00001	TO-252AA	3,000pcs / 13" reel	D40N06A	Halogen free
PJP40N06A_T0_00001	TO-220AB	50pcs / Tube	P40N06A	Halogen free

Mounting Pad Layout







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